

Stellaris[®] LM3S1P51 RevC Errata

This document contains known errata at the time of publication for the Stellaris[®] LM3S1P51 microcontroller. The table below summarizes the errata and lists the affected revisions. See the data sheet for more details.

See also the ARM® Cortex[™]-M3 errata, ARM publication number PR326-PRDC-009450 v2.0.

Date	Revision	Description
July 2010	3.1	 Added issue "The RTRIS bit in the UARTRIS register is only set when the interrupt is enabled" on page 15. Clarified workaround and corrected silicon revisions affected on "Slow V_{DD} ramp may occasionally cause device failures" on page 16.
June 2010	3.0	 Added statement to "Reset patch is required" on page 4 that the vector table must be located at address 0x1000.
June 2010	2.9	Clarified "Reset patch is required" on page 4.
		 Added issue "Mass erase must not be used if Flash protection bits are used" on page 8.
		 Added issue "Page erase or program must not be performed on a protected Flash page" on page 8.
		Added issue "Slow V _{DD} ramp may occasionally cause device failures" on page 16.
May 2010	2.8	Added issue "Wake-up time from Hibernation may exceed specifications" on page 3.
		 Added issue "Hibernation Module draws a higher current than is specified in the data sheet" on page 4.
		 Clarified "Reset patch is required" on page 4.
		 Added issue "Boot Loader in ROM is unusable" on page 7.
April 2010	2.7	Added information to "Software Considerations" appendix.
		 Additional minor clarifications and corrections.
April 2010	2.6	Started tracking revision history.

Erratum Number	Erratum Title	Revision(s) Affected
1.1	VDD3ON mode may not be used	C1, C3
1.2	Wake-up time from Hibernation may exceed specifications	C1
1.3	Writes to Hibernation module registers sometimes fail	C1, C3
1.4	Hibernation Module 4.194304-MHz oscillator supports a limited range of crystal load capacitance values	C1, C3
1.5	Hibernation Module draws a higher current than is specified in the data sheet	C1, C3

Erratum Number	Erratum Title	Revision(s) Affected
2.1	Reset patch is required	C1
2.2	Deep-Sleep mode should not be used	C1, C3
3.1	Boot Loader in ROM is unusable	C1
4.1	Mass erase must not be used if Flash protection bits are used	C1, C3
4.2	Page erase or program must not be performed on a protected Flash page	C1, C3
5.1	The μDMA controller fails to generate capture mode DMA requests from Timer A in the Timer modules	C1, C3
6.1	Schmitt input feature does not function correctly	C1
7.1	The General-Purpose Timer match register does not function correctly in 32-bit mode	C1, C3
7.2	A spurious DMA request is generated when the timer rolls over in Input-Edge Time mode	C1, C3
7.3	A spurious DMA request is generated when the timer rolls over the 16-bit boundary	C1, C3
7.4	The value of the prescaler register is not readable in Edge-Count mode	C1, C3
7.5	ADC trigger and Wait-on-Trigger may assert when the timer is disabled	C1, C3
7.6	Wait-on-Trigger does not assert unless the TnOTE bit is set	C1, C3
7.7	Do not enable match and timeout interrupts in 16-bit PWM mode	C1, C3
7.8	Do not use µDMA with 16-bit PWM mode	C1, C3
7.9	Writing the GPTMTnV register does not change the timer value when counting up	C1, C3
7.10	The prescaler does not work correctly when counting up in periodic or one-shot mode	C1, C3
7.11	Snapshot must be enabled in both Timer A and B when in 32-bit snapshot mode	C1, C3
8.1	Writes to Watchdog Timer 1 module WDTLOAD register sometimes fail	C1, C3
9.1	ADC hardware averaging produces erroneous results in differential mode	C1, C3
10.1	Phantom interrupts occur in Smart Card mode	C1
10.2	The RTRIS bit in the UARTRIS register is only set when the interrupt is enabled	C1, C3
11.1	Startup time after power-on reset or hibernation exceeds specification	C1, C3
11.2	Slow V_{DD} ramp may occasionally cause device failures	C1

1 Hibernation Module

1.1 VDD3ON mode may not be used

Description:

The VDD3ON mode may not be used.

Workaround:

None. Do not use the VDD3ON mode to enter hibernation.

Silicon Revision Affected:

C1, C3

Fixed:

Not yet fixed.

1.2 Wake-up time from Hibernation may exceed specifications

Description:

The Hibernation module is specified to resume operation after the $\overline{\text{WAKE}}$ signal is asserted within 124 µs, however operation may not resume for 30 ms in some cases. (The "Hibernation Module AC Characteristics" table in the DS indicates 10 ms.)

Workaround:

None.

Silicon Revision Affected:

C1

Fixed:

Fixed in Rev C3.

1.3 Writes to Hibernation module registers sometimes fail

Description:

Due to a synchronization issue with the independent clock domain of the Hibernation module, writes may sometimes fail, even though the WRC bit in the **HIBCTL** register is set after the write occurs.

Workaround:

After performing a write to any Hibernation module register or non-volatile memory, read the contents back and verify that they are correct. If they are incorrect, perform the write operation again.

Silicon Revision Affected:

C1, C3

Fixed:

Not yet fixed.

1.4 Hibernation Module 4.194304-MHz oscillator supports a limited range of crystal load capacitance values

Description:

For some 4.194304-MHz crystals, the manufacturer-recommended crystal value may be outside of the capabilities of the hibernate module oscillator. If the crystal manufacturer's recommended load capacitance is used, the hibernate oscillator may fail to start.

For a parallel-resonant oscillator circuit, the total load capacitance C_L (as specified by the manufacturer) is calculated as follows:

$$C_{L} = (C_{1} * C_{2}) / (C_{1} + C_{2}) + C_{S}$$

Due to the workaround, C_1 and C_2 are limited to 20 pF. Using 3 pF for stray capacitance (C_S), the formula above shows that a crystal with C_L of 13 pF is the highest value supported due to this errata. Refer to the crystal datasheet to determine which crystals have an acceptable load capacitance (CI) range.

Workaround:

Use load capacitors of 20 pF or less (18 pF is typical). Note that for some crystals, this value may pull the oscillator frequency slightly away from the crystal manufacturer's specified accuracy. Your crystal manufacturer can provide this information.

Alternatively, use an external 32.768-kHz oscillator as the source for the Hibernation module clock.

Silicon Revision Affected:

C1, C3

Fixed:

Not yet fixed.

1.5 Hibernation Module draws a higher current than is specified in the data sheet

Description:

The "Preliminary Current Consumption" table in the data sheet specifies that the Hibernation module's nominal current draw when not using the RTC (I_{HIB_NORTC}) is 8 µA and is 18 µA when using the RTC (I_{HIB_RTC}). The nominal values are actually 24 µA and 34 µA.

Workaround:

None.

Silicon Revision Affected:

C1, C3

Fixed:

Not yet fixed.

2 Internal Memory

2.1 Reset patch is required

Description:

An error in the design of a production test mode can cause software to crash in certain rare instances. A reset patch pre-programmed into Flash memory provides an effective workaround.

In addition, there is an approximately 1 in 100,000 chance that executing any type of reset other than a power-on reset may cause the core to hang. These reset types include:

- Watchdog reset
- Brown-out reset
- Software reset

- Reset pin assertion
- Main oscillator fail

Workaround:

The required software change is pre-programmed into the 4-KB block of Flash memory at address 0x0000.0000 and is protected from being erased or programmed. In addition, the second 2-KB block at address 0x0000.0800 is not readable. The patch also requires an interrupt handler, which must be hooked to the Flash interrupt in the main vector table.

The patch places the following requirements on applications:

- Interrupts must be enabled for a minimum of 5 continuous seconds every 2 hours because the patch runs in the context of the Flash interrupt handler.
- Any interrupt that is higher priority than the Flash interrupt may not program or erase Flash memory.
- Applications must be aware that the master Cortex-M3 interrupt in the NVIC is enabled as part of the workaround initialization, which is likely to occur before the application would normally enable interrupts. Care must be taken to ensure that this condition is taken into account when initializing other peripherals and interrupts.
- On rare occasions, a Flash interrupt may take up to 2 ms to be processed. Worst case, this may happen twice per every 12 hours of running time.
- The ROM boot loader does not function. If you need a boot loader, put the StellarisWare boot loader in Flash memory, ensuring that the linker file has a start address of 0x0000.1000
- The option to force the ROM boot loader to execute at reset with an external pin does not function. Changing the PORT and PIN fields of the Boot Configuration (BOOTCFG) register has no effect.

To protect the pre-programmed code in Flash memory, the following restrictions apply to the use of the device:

- The mass erase function using the MERASE bit in the Flash Memory Control (FMC) register does not erase the part.
- A toggle-mass erase must not be executed, meaning that the debug port unlock sequence in LMFlash Programmer must not be executed.
- The vector table must be located at address 0x1000 and application code must be configured to run from address 0x1000.
- Because the first 4-KB block of Flash memory is protected, the Flash Memory Protection Read Enable 0 (FMPRE0) and Flash Memory Protection Program Enable 0 (FMPPE0) registers cannot be used by application software.

Refrain from implementing the internal watchdog, brown-out, and main oscillator failure resets and don't use an external reset. If the device hangs, execute a power-on reset.

A software reset can still be executed by calling WorkaroundSysCtlReset() in the place of SysCtlReset() and ROM_SysCtlReset().

See Appendix A on page 17 for further information on how to implement code for these devices and use debugging tools.

Note that two versions of the patch code have been released. Devices that have the patch code pre-programmed in Flash memory have a silver metallic dot located on the pin1 indicator. Devices that have the patch code plus a UART-only flash loader pre-programmed in Flash memory (see "Boot Loader in ROM is unusable" on page 7) have a date code of 05 or later. See Part Marking Examples below. In addition, a 32-bit date code is programmed at address 0x0000.07F8 and a 32-bit patch revision number programmed at address 0x0000.07FC.

Part Marking Examples

The silver metallic dot on the part indicating that the patch code was pre-programmed in Flash memory looks like the following:



Parts with a date code of 05 (May 2010) or later contain the patch plus a UART-only flash loader (see "Boot Loader in ROM is unusable" on page 7). To determine the date code of your part, look at the third line in the part markings, at the fourth and fifth characters following the dash (highlighted in red below). The first number after the dash indicates the last decimal digit of the year. The next character indicates the month, in hexadecimal. So, in the below example, the 9B indicates a date code of November 2009.



The table below shows some example date codes:

Date Code	Date
9B	November 2009
9C	December 2009
01	January 2010
02	February 2010
03	March 2010
04	April 2010
05	May 2010
06	June 2010
07	July 2010
08	August 2010
09	September 2010
0A	October 2010
0B	November 2010
0C	December 2010

Silicon Revision Affected:

C1

Fixed:

Fixed in Rev C3, although a side effect of the fix is that all of the reset sources listed under the "Description" head above will take approximately 2 ms to complete on C3 devices.

2.2 Deep-Sleep mode should not be used

Description:

Deep-sleep mode should not be used.

Workaround:

Use Sleep or Hibernation mode.

Silicon Revision Affected:

C1, C3

Fixed:

Not yet fixed.

3 ROM

3.1 Boot Loader in ROM is unusable

Description:

The reset patch that is pre-programmed into Flash memory (see "Reset patch is required" on page 4) makes the Boot Loader in ROM unusable.

Workaround:

On parts with a date code of 05 or later (see "Part Marking Examples" on page 6), a UART-only flash loader is pre-programmed into Flash memory at 0x1000 (similar to the serial flash loader that is provided on Stellaris parts that do not have a ROM). This flash loader uses the same protocol as boot loader in ROM but only operates via UART0. Unlike the boot loader, it is a one-time-use loader; if true boot loader functionality is required, the flash loader should be used to load a boot loader. LM Flash Programmer can be used to communicate with the flash loader by selecting the serial interface on the main tab.

For more details on the flash loader protocol, see the UART section in the Boot Loader appendix in your data sheet.

Silicon Revision Affected:

C1

Fixed:

Fixed in Rev C3.

4 Flash

4.1 Mass erase must not be used if Flash protection bits are used

Description:

The mass erase function using the MERASE bit in the Flash Memory Control (FMC) register must not be used in systems that clear any of the Flash Memory Protection Read Enable n (FMPREn) or Flash Memory Protection Program Enable n (FMPPEn) bits. For Rev C1 devices, this means that mass erase must not be used because bits in the FMPRE0 and FMPPE0 registers are cleared to protect the reset patch that is stored in the first block of Flash memory. For Rev C3 devices, mass erase can be used as long as none of the FMPREn or FMPPEn bits are cleared.

Workaround:

Erase Flash memory with the page erase function using the ERASE bit in the **FMC** register instead of the mass erase function.

Silicon Revision Affected:

C1, C3

Fixed:

Not yet fixed.

4.2 Page erase or program must not be performed on a protected Flash page

Description:

The erase function using the ERASE bit in the **Flash Memory Control (FMC)** register and the program function using the WRITE bit in the **FMC** register or the WRBUF bit in the **FMC2** register must not be used in systems that clear the bit in **FMPREn** or **FMPPEn** that corresponds to that page of Flash. For C1 devices, this means that erase and program of locations 0x0 through 0xFFF must not be used because bits in the **FMPRE0** and **FMPPE0** registers are cleared to protect the reset patch that is stored in the first block of Flash memory. For Rev C3 devices, erase and program can be used as long as neither of the corresponding **FMPREn** or **FMPPEn** bits are cleared.

Workaround:

Only erase and program memory that is not protected by the corresponding **FMPPEn** or **FMPPEn** bits.

Silicon Revision Affected:

C1, C3

Fixed:

Not yet fixed.

5 μDMA

5.1 The µDMA controller fails to generate capture mode DMA requests from Timer A in the Timer modules

Description:

The μ DMA controller fails to generate DMA requests from Timer A in the General-Purpose Timer modules when in the Event Count and Event Time modes.

Workaround:

Use Timer B.

Silicon Revision Affected:

C1, C3

Fixed:

Not yet fixed.

6 GPIO

6.1 Schmitt input feature does not function correctly

Description:

The Schmitt input on digital inputs may generate spurious transitions when connected to low slew-rate signal sources. If the input signal has a slew rate of less than $1V/\mu s$, a negative edge can generate several additional transitions into the microcontroller even though the input signal is still within the hysteresis band. Positive edges are not affected.

The additional transitions can cause anomalous operation in any peripherals or GPIOs that use digital inputs. Most at risk are peripherals that use pull-up resistors (l^2C , GPIOs) or that typically involve slower signals (sensor inputs). This behavior can affect the noise immunity of digital inputs. As a result, arbitration may be lost during communication when the l^2C module is the master.

Workaround:

Ensure that all signals connected to digital inputs have a slew rate of at least $1V/\mu$ s. In some applications, reducing the resistance value of pull-up and pull-down resistors may be necessary. Note that R-C filters, such as low pass, on digital input signals should only be used if the slew-rate is still above $1V/\mu$ s, or if additional transitions on the falling edge can be tolerated. Adding an external Schmitt-trigger circuit is a requirement for circuits where slow transitions are unavoidable and system noise levels are high.

Silicon Revision Affected:

C1

Fixed:

Fixed in Rev C3.

7 General-Purpose Timer

7.1 The General-Purpose Timer match register does not function correctly in 32-bit mode

Description:

The **GPTM Timer A Match (GPTMTAMATCHR)** register triggers a match interrupt and a DMA request, if enabled, when the lower 16 bits match, regardless of the value of the upper 16 bits.

Workaround:

None.

Silicon Revision Affected:

C1, C3

Fixed:

Not yet fixed.

7.2 A spurious DMA request is generated when the timer rolls over in Input-Edge Time mode

Description:

When the timer is in Input-Edge Time mode and rolls over after the terminal count, a spurious DMA request is generated.

Workaround:

Either ignore the spurious interrupt, or capture the edge time into a buffer via DMA, then the spurious interrupt can be detected by noting that the captured value is the same as the previous capture value.

Silicon Revision Affected:

C1, C3

Fixed:

Not yet fixed.

7.3 A spurious DMA request is generated when the timer rolls over the 16-bit boundary

Description:

When the timer is in 32-bit periodic or one-shot mode and is enabled to generate periodic DMA requests, a spurious DMA request is generated when the timer rolls past 0x0000FFFF.

Workaround:

Only use DMA with a 16-bit periodic timer.

Silicon Revision Affected:

C1, C3

Fixed:

Not yet fixed.

7.4 The value of the prescaler register is not readable in Edge-Count mode

Description:

In Edge-Count mode, the prescaler is used as an 8-bit high order extension to the 16-bit counter. When reading the **GPTM Timer n (GPTMTnR)** register as a 32-bit value, the bits [23:16] always contain the initial value of the **GPTM Timer n Prescale (GPTMTnPR)** register, that is, the "load" value of the 8-bit extension.

Workaround:

None.

Silicon Revision Affected:

C1, C3

Fixed:

Not yet fixed.

7.5 ADC trigger and Wait-on-Trigger may assert when the timer is disabled

Description:

If the value in the **GPTM Timer n Match (GPTMTnMATCHR)** register is equal to the value of the timer counter and the TnOTE bit in the **GPTM Control (GPTMCTL)** register is set, enabling the ADC trigger, the trigger fires even when the timer is disabled (the TnEN bit in the **GPTMCTL** register is clear). Similarly, if the value in the **GPTMTnMATCHR** register is equal to the value of the timer counter and the TnWOT bit in the **GPTM Timer n Mode (GPTMTnMR)** register is set, enabling the Wait-on-Trigger mode, the trigger fires even when the timer is disabled.

Workaround:

Enable the timer before setting the TnOTE bit. Also, for the Wait-on-Trigger mode, ensure that the timers are configured in the order in which they will be triggered.

Silicon Revision Affected:

C1, C3

Fixed:

Not yet fixed.

7.6 Wait-on-Trigger does not assert unless the TnOTE bit is set

Description:

Wait-on-Trigger does not assert unless the **TNOTE** bit is set in the **GPTMCTL** register.

Workaround:

If the TnWOT bit in the **GPTM Timer n Mode (GPTMTnMR)** register is set, enabling the Wait-on-Trigger mode, the TnOTE bit must also be set in the **GPTMCTL** register in order for the Wait-on-Trigger to fire. Note that when the TnOTE bit is set, the ADC trigger is also enabled.

Silicon Revision Affected:

C1, C3

Fixed:

Not yet fixed.

7.7 Do not enable match and timeout interrupts in 16-bit PWM mode

Description:

16-bit PWM mode generates match and timeout interrupts in the same manner as periodic mode.

Workaround:

Ensure that any unwanted interrupts are masked in the **GPTMTnMR** and **GPTMIMR** registers.

Silicon Revision Affected:

C1, C3

Fixed:

Not yet fixed.

7.8 Do not use µDMA with 16-bit PWM mode

Description:

16-bit PWM mode generates match and timeout μDMA triggers in the same manner as periodic mode.

Workaround:

Do not use μ DMA to transfer data when the timer is in 16-bit PWM mode.

Silicon Revision Affected:

C1, C3

Fixed:

Not yet fixed.

7.9 Writing the GPTMTnV register does not change the timer value when counting up

Description:

When counting up, writes to the **GPTM Timer n Value (GPTMTnV)** register do not change the timer value.

Workaround:

None.

Silicon Revision Affected:

C1, C3

Fixed:

Not yet fixed.

7.10 The prescaler does not work correctly when counting up in periodic or one-shot mode

Description:

When counting up, the prescaler does not work correctly in 16-bit periodic or snap-shot mode.

Workaround:

Do not use the prescaler when counting up in 16-bit periodic or snap-shot mode.

Silicon Revision Affected:

C1, C3

Fixed:

Not yet fixed.

7.11 Snapshot must be enabled in both Timer A and B when in 32-bit snapshot mode

Description:

When a periodic snapshot occurs in 32-bit periodic mode, only the lower 16-bit are stored into the **GPTM Timer A (GPTMTAR)** register.

Workaround:

If both the TASNAPS and TBSNAPS bits are set in the **GPTM Timer A Mode (GPTMTAMR)** register, the entire 32-bit snapshot value is stored in the **GPTMTAR** register.

Silicon Revision Affected:

C1, C3

Fixed:

Not yet fixed.

8 Watchdog Timer 1

8.1 Writes to Watchdog Timer 1 module WDTLOAD register sometimes fail

Description:

Due to the independent clock domain of the Watchdog Timer 1 module, writes to the **Watchdog Load (WDTLOAD)** register may sometimes fail, even though the WRC bit in the **WDTCTL1** register is set after the write occurs.

Workaround:

After performing a write to the **WDTLOAD** register, read the contents back and verify that they are correct. If they are incorrect, perform the write operation again.

Silicon Revision Affected:

C1, C3

Fixed:

Not yet fixed.

9 ADC

9.1 ADC hardware averaging produces erroneous results in differential mode

Description:

The implementation of the ADC averaging circuit does not work correctly when the ADC is sampling in differential mode and the difference between the voltages is approximately 0.0V.

Workaround:

Do not use hardware averaging in differential mode. Instead, use the FIFO to store results and average them in software.

Silicon Revision Affected:

C1, C3

Fixed:

Not yet fixed.

10 UART

10.1 Phantom interrupts occur in Smart Card mode

Description:

In Smart Card mode, after receiving a valid TX interrupt, phantom parity error interrupts occur, even though all **UARTRIS** and **UARTMIS** bits are clear.

Workaround:

Make sure to always clear the parity error interrupt in the interrupt handler, even when the PERIS and PEMIS bits are clear.

Silicon Revision Affected:

C1

Fixed:

Fixed in Rev C3.

10.2 The RTRIS bit in the UARTRIS register is only set when the interrupt is enabled

Description:

The RTRIS (UART Receive Time-Out Raw Interrupt Status) bit in the **UART Raw Interrupt Status** (UARTRIS) register should be set when a receive time out occurs, regardless of the state of the RTIM enable bit in the UART Interrupt Mask (UARTIM) register. However, currently the RTIM bit must be set in order for the RTRIS bit to be set when a receive time out occurs.

Workaround:

For applications that require polled operation, the RTIM bit can be set while the UART interrupt is disabled in the NVIC using the IntDisable(n) function in the StellarisWare Peripheral Driver Library, where n is 21, 22, or 49 depending on whether UART0, UART1 or UART2 is used. With this configuration, software can poll the RTRIS bit, but the interrupt is not reported to the NVIC.

Silicon Revision Affected:

C1, C3

Fixed:

Not yet fixed.

11 Electrical Characteristics

11.1 Startup time after power-on reset or hibernation exceeds specification

Description:

When performing a power-on reset or waking from hibernation, the startup time is approximately 1.66 ms longer than specified in the data sheet.

Workaround:

None.

Silicon Revision Affected:

C1, C3

Fixed:

Not yet fixed.

11.2 Slow V_{DD} ramp may occasionally cause device failures

Description:

A slow V_{DD} power-on ramp may cause the LDO to start improperly. When this occurs, the microcontroller may not come out of reset properly, causing it to be in an unknown state. In most cases, a subsequent POR addresses the issue. In rare cases, flash corruption may occur. If flash corruption occurs, a POR will not address the issue.

Asserting the external \overline{RST} signal during a slow V_{DD} ramp does not resolve this issue.

Workaround:

The V_{DD} power supply must have a ramp-up time of 1 ms or less (5% to 90%). Because the use of the brown-out reset is not possible due to "Reset patch is required" on page 4, ensure that the power supply is stable. If the V_{DD} voltage drops, the voltage should collapse to 5% of VDD. An external Supply Voltage Supervisor (SVS) controlling a power switch may be used to meet these requirements.

Silicon Revision Affected:

C1

Fixed:

Fixed on C3.

Appendix A Software considerations for devices with the software patch in Flash memory

A.1. Flash workaround interrupt handler

The "Reset patch is required" on page 4 erratum requires an interrupt handler which must be hooked to the Flash interrupt in the main vector table. This handler, WorkaroundIntHandler(), is located at address 0x880. A user's Flash Interrupt Handler should contain code similar to the following:

```
11
// The FLASH workaround interrupt handler
11
void
FlashIntHandler(void)
{
  11
  // Call the PATCH Code Interrupt handler
  11
  ((void (*)(void))0x881)();
}
... or ...
#define WorkaroundIntHandler ((void (*)(void))0x881)
11
// The FLASH workaround interrupt handler
11
void
FlashIntHandler(void)
{
  11
  // Call the PATCH Code Interrupt handler
  11
  WorkaroundIntHandler();
}
```

Alternatively, the vector table could simply be hard-coded as follows, to avoid one layer of function calls.

...

```
IntDefaultHandler, // Analog Comparator 2
IntDefaultHandler, // System Control (PLL, OSC, BO)
0x00000881, // FLASH Control
IntDefaultHandler, // GPIO Port F
IntDefaultHandler, // GPIO Port G
```

•••

A.2. Software reset workaround

The "Reset patch is required" on page 4 erratum requires that SysCtlReset() and ROM_SysCtlReset() not be used. Instead, the following code should be used:

A.3. Debugging considerations

When using debugging tools with the software patch, certain considerations must be observed as detailed in the following sections.

A.3.1. Keil RealView® MDK-ARM Microcontroller Development Kit

If the debugger is configured to simply reset/connect, it attempts to disassemble code in a protected region of Flash memory. The simple solution is to configure the debugger to "load/run to main". With this configuration, the patch code gets run and the Flash interrupt gets enabled. The PC runs to the main() function when the debugger starts. This option can be found in: Project \Box Options for target 'roject name>' as shown in Figure A-1 on page 18.

Figure A-1. Navigating to the "Run to Main()" Option

👿 he	ello - j	µVision	4											
<u>F</u> ile	<u>E</u> dit	<u>V</u> iew	<u>Pro</u>	ject	Fl <u>a</u> sh	<u>D</u> ebug	Pe <u>r</u> ipherals	<u>T</u> ools	<u>s</u> vcs	<u>W</u> indow	<u>H</u> elp			
				New	µ <u>V</u> ision	Project								
:				New	Multi-P	roject <u>W</u> o	orkspace							
Projec				<u>O</u> per	n Projec	t								
	a hello			<u>C</u> los	e Projec	t								
Ē	- 📇 So	-		<u>E</u> xpo	rt									÷
	3			<u>M</u> an	age									•
		uartst) braries		<u>S</u> elec	t Device	for Targ	et 'hello'							
		driver			o <u>v</u> e Item									
Ė)- 😑 D	cument	×	O <u>p</u> ti	ons for	Target 'h	ello'							Alt+F7
	<u></u>			Clear	n <u>t</u> arget									
				<u>B</u> uild	d target									F7

When the Options window opens, select the Debug tab. Under Debug select "Run to main()" as shown in Figure A-2 on page 19.

Figure A-2. Selecting the "Run to Main()" Option

Options for Target 'hello'	↓ X
Device Target Output Listing User C/C++ Asm	Linker Debug Utilities
C Use Simulator Settings	
✓ Load Application at Startup ✓ Run to main() Initialization File:	✓ Load Application at Startup ✓ Run to main()
Edit	Edit
Restore Debug Session Settings	Restore Debug Session Settings
I Breakpoints I Toolbox	Image: wide of the second s
Watchpoints & PA	Watchpoints
Memory Display	Memory Display
CPU DLL: Parameter:	Driver DLL: Parameter:
SARMCM3.DLL	SARMCM3.DLL
Dialog DLL: Parameter:	Dialog DLL: Parameter:
DLM.DLL -pLM3S9B90	TLM.DLL pLM3S9B90
, ,	
OK Car	ncel Defaults Help

A.3.2. Code Red Tools Suite

Code Red Tools Suite works seamlessly. Upon startup of the debugger (in default settings), the patch code gets run and the Flash interrupt gets enabled. The code starts executing at the main() function.

A.3.3. CodeSourcery Sourcery G++

CodeSourcery does not run the patch code by default; it starts at the main() function. To get the patch code to run, manually set the stack pointer (SP) and program counter (PC). These register can be set by accessing the "Debugger Configurations…" tab. To do this, right click on the project and select Debug As \Box Debug Configurations as shown in Figure A-3 on page 20.

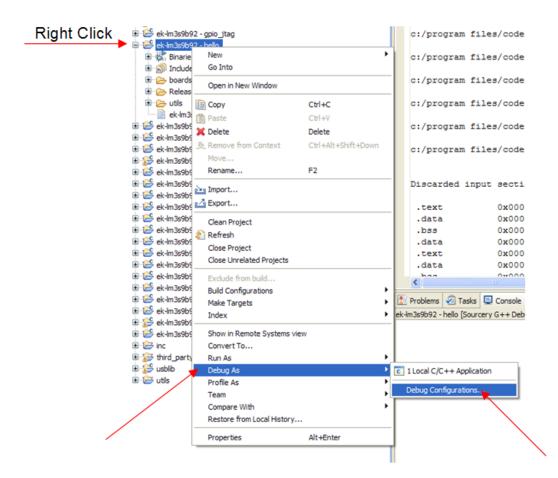


Figure A-3. Navigating to the Debugger Configurations Window

I had a hard time finding configuration options for the flash programmer and the debugger. Fortunately, the flash programmer does page erases by default, which allows us to program the part without any issues. The problem with the CodeSourcery debugger is that it does not run through the patch code by default, it just starts at your main() function. To get the patch code to run, you have to manually set the stack pointer (SP) and program counter (PC). The first thing you need to do is access the "Debugger Configurations…" tab. To do this, right click on your project and select Debug As Debug Configurations.

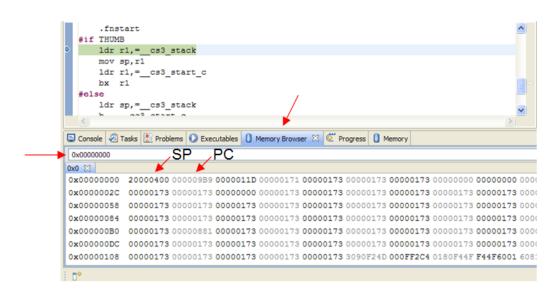
Once the "Debug Configurations" window is up, select the "Debugger" tab and check "Stop on startup at:" and enter "main" in the text box; also check "Stop on first assembler instruction" as shown in Figure A-4 on page 21.

Configurations	X
Create, manage, and run cor	nfigurations
Ype filter text • ek-Im3s9b92 - gpio. • ek-Im3s9b92 - hello • ek-Im3s9b92 - hello • ek-Im3s9b92 - intern • ek-Im3s9b92 - mpu. • ek-Im3s9b92 - grad • ek-Im3s9b92 - grad • ek-Im3s9b92 - uma • ek-Im3s9b92 - uma • ek-Im3s9b92 - udma • ek-Im3s9b92 - udma	Name: ek-lm3s9b92 - hello Image: Main 64* Arguments Image: Environment Stop Debugger Common Debugger: Sourcery G++ Debug Sprite for Stellaris EABI Image: Image:
?	Qebug Close

Figure A-4. Configuring the Debugger for Correct Operation

Once the debugger is started, go to the "Memory Browser" window at the bottom of the screen and enter address 0x00000000. The first 2 locations show you the SP and PC for the patch as shown in Figure A-5 on page 22.





Go to the "Registers" tab and enter these values for the SP and PC manually as shown in Figure A-6 on page 22.

+\arm-stellaris-eabi\lib\src\start.S - Sourcery G++ IDE		
월 - 월 - 🏷 🔶 -		
		•
🍇 🖉 🤣 🕨 🔲 🔳 🖉 🔍 🖘 🕫 💷 👘 🏹 🕸 🏹	Comparison of the second	essions 👫 Registers 🔀 🛋 Modu
10 110 (0 m m l + 0		
:49 AM) (Suspended)	Name	Value
	😑 👬 Main	
g++\arm-stellaris-eabi\lib\src\start.S:26 0x00001560	010 rO	0x0
h-2-06-02 h-11-10-116-116 (4/20 (10 10-10 404)	1010 0101 r1	0x0
-lm3s9b92 - hello\Release\hello.axf (4/20/10 10:49 AM)	1010 r2	0x0
	1010 r3	0x0
	1010 0101 r4	0x0
	1010 r5	0x0
	1010 r6	0x0
	1010 r7	0x0
	10101 r8	0x0
	1111 r9	0x0
	1010 r 10	0x0
	0101 r11	0x0
	0101 r12	0x0
	aller sp	0x20000400
	1010 lr	0xffffffff
	Stati pc	0x000009b8 ┥
	1010 0101 xpsr	0x1000000
	and sp_main	0x2000029c
	and sp process	0x0

Figure A-6. Entering the SP and PC Manually

Once the new PC and SP have been entered, click the run button. The debugger will now successfully run through the patch code and stop at the main() function.

A.3.4. Code Composer Studio

CCS does not work by default - it hangs when the debugger loads because the default flash erase option is mass erase (which won't work because the patch code is write protected). The flash erase option must be changed to page erase. To do this, start a debug session (even though it won't work correctly) to get access to the Flash settings. Once in the debug session, go to Tools
On-Chip Flash then under Erase select "Necessary Pages Only (for Program Load)" as shown in Figure A-7 on page 23.

Cheat Sheets 🔟 On-Chip Flash 🗙 Help		-
pe filter text On-Chip Flash Generic Debugger Options GEL Files ARM Advanced Features Memory Map	On-Chip Flash (CORTEX_M3) Image: Constant of the second secon	

Figure A-7. Changing the Flash Erase Option

To get the patch code to run, a "Core Reset" must be executed in the IDE. Go to Target
Reset
Reset
Core Reset to reset the core, which results in the patch code being run. To configure the IDE to
perform a core reset automatically, go to Target
Properties and on the left hand side of the window
select CCS Debug. Once you select CCS Debug click on Target on the right hand side of the window.
Scroll down until you see an option that says "Reset the target on program load or restart" and select
it as shown in Figure A-8 on page 24.

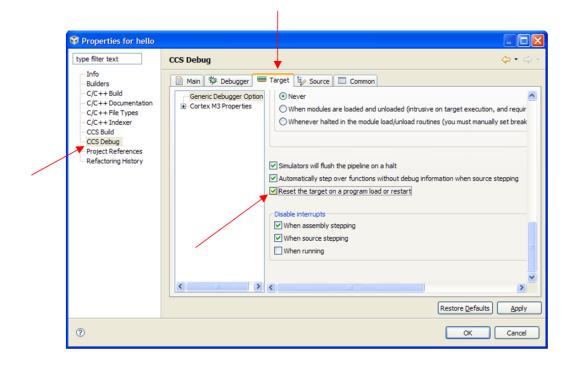


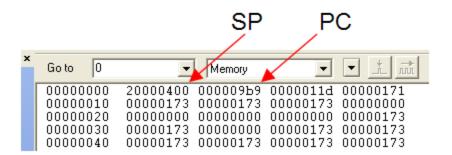
Figure A-8. Configuring the IDE to Reset on Program Load

A.3.5. IAR Embedded Workbench™ for ARM and Cortex-M3

IAR has problems executing code at address 0x0000.0000 if is not the main() application (such as bootloader examples). As a result, the PC and SP must be manually loaded. The values to load can be found at address 0x0000.0000 and 0x0000.0004 in the memory window and loaded into the PC (0x000009B8) and SP (0x20000400) as shown in Figure A-9 on page 25.

egister		×
Current CPU Re	egisters 💌	
RO	= 0x00000000	BASEPRI_M
R1	= 0x2000010C	FAULTHASK
R2	$= 0 \times 000000000$	± CONTROL
R3	$= 0 \times 000000000$	
R4	$= 0 \times 000000000$	
R5	= 0x00000000	
R6	= 0x00000000	
R7	= 0x00000000	
R8	= 0x00000000	
R9	= 0x00000000	
R10	= 0x00000000	
R11	= 0x00000000	
R12	= 0x00000000	
R13 (SP)	= 0x20000400	-
R14 (LR)	= 0x00001513	
APSR	= 0x60000000	
IPSR	= 0x00000000	
EPSR	= 0x01000000	
PC	= 0x <mark>000009B8</mark>	-
PRIMASK	= 0x00000000	
BASEPRI	= 0x00000000	
16		
		>

Figure A-9. Manually Configuring the PC and SP Registers



Set a breakpoint at the main() function and run the program. This process causes the Flash memory interrupt to be enabled and the debugger to operate as expected. Note: Every time you startup the debugger or do a reset in the IDE, you need to perform this sequence.

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Texas Instruments 108 Wild Basin, Suite 350 Austin, TX 78746 http://www.ti.com/stellaris

